



THE DATASHEET OF 63CNQ100



International
IR Rectifier

163CNQ... SERIES

SCHOTTKY RECTIFIER

160 Amp

$$I_{F(AV)} = 160 \text{ Amp}$$

$$V_R = 60/100V$$

Major Ratings and Characteristics

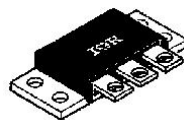
Characteristics	Values	Units
$I_{F(AV)}$ Rectangular waveform	160	A
V_{RRM} range	60/100	V
I_{FSM} @tp=5 μ s sine	9000	A
V_F @80Apk, $T_J=125^\circ\text{C}$ (per leg)	0.80	V
T_J range	-55 to 175	$^\circ\text{C}$

Description/ Features

The 163CNQ isolated center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 $^\circ\text{C}$ junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- 175 $^\circ\text{C}$ T_J operation
- Not Isolated heatsink
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Low profile, high current package

Case Styles



TO-249AA

Voltage Ratings

Part number	163CNQ060	163CNQ080	163CNQ090	163CNQ100
V_R Max. DC Reverse Voltage (V)	60	80	90	100
V_{RWM} Max. Working Peak Reverse Voltage (V)				

Absolute Maximum Ratings

Parameters	163CNQ	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 5	160	A	50% duty cycle @ $T_C = 122^\circ\text{C}$, rectangular waveform
Per Device Per Leg	80		
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current (Per Leg) * See Fig. 7	9000	A	5 μs Sine or 3 μs Rect. pulse 10ms Sine or 6ms Rect. pulse Following any rated load condition and with rated V_{RRM} applied
	800		
E_{AS} Non-Repetitive Avalanche Energy (Per Leg)	15	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 1$ Amps, $L = 30$ mH
I_{AR} Repetitive Avalanche Current (Per Leg)	1	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical

Electrical Specifications

Parameters	163CNQ	Units	Conditions
V_{FM} Max. Forward Voltage Drop (Per Leg) * See Fig. 1 (1)	0.98	V	@ 80A $T_J = 25^\circ\text{C}$
	1.17	V	@ 160A
	0.80	V	@ 80A $T_J = 125^\circ\text{C}$
	0.96	V	@ 160A
I_{RM} Max. Reverse Leakage Current (Per Leg) * See Fig. 2 (1)	1.5	mA	$T_J = 25^\circ\text{C}$ $V_R = \text{rated } V_R$
	20	mA	$T_J = 125^\circ\text{C}$
C_T Max. Junction Capacitance (Per Leg)	1400	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) 25°C
L_S Typical Series Inductance (Per Leg)	8.0	nH	Measured from terminal hole to terminal hole
dv/dt Max. Voltage Rate of Change (Rated V_R)	10000	V/ μs	

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	163CNQ	Units	Conditions
T_J Max. Junction Temperature Range	-55 to 175	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-55 to 175	$^\circ\text{C}$	
R_{thJC} Max. Thermal Resistance Junction to Case (Per Leg)	0.70	$^\circ\text{C}/\text{W}$	DC operation * See Fig. 4
R_{thJC} Max. Thermal Resistance Junction to Case (Per Package)	0.35	$^\circ\text{C}/\text{W}$	DC operation
R_{thCS} Typical Thermal Resistance, Case to Heatsink	0.10	$^\circ\text{C}/\text{W}$	Mounting surface, smooth and greased
wt Approximate Weight	58 (2.0)	g (oz.)	
T Mounting Torque	Min.	40 (35)	Kg-cm (lbf-in)
	Max.	58 (50)	
Case Style	TO-249AA	JEDEC	

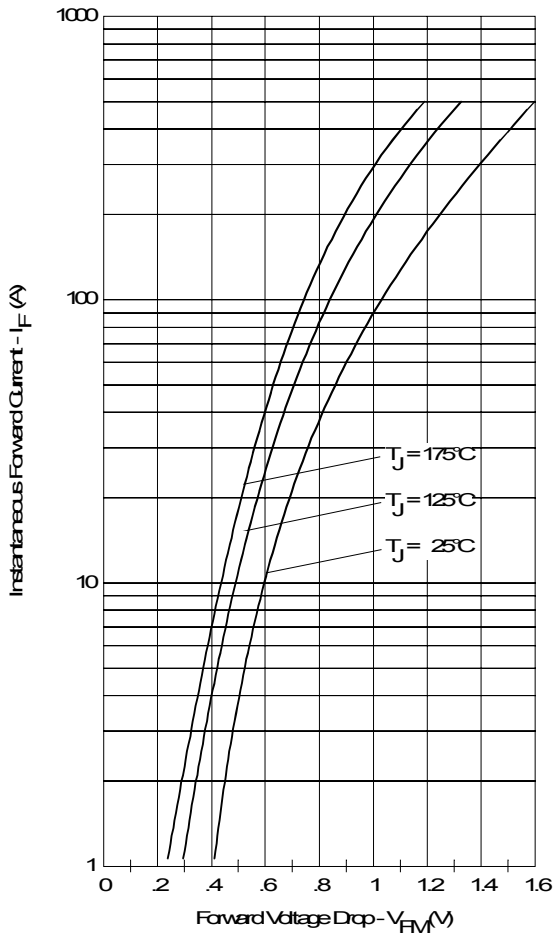


Fig. 1 - Max. Forward Voltage Drop Characteristics (Per Leg)

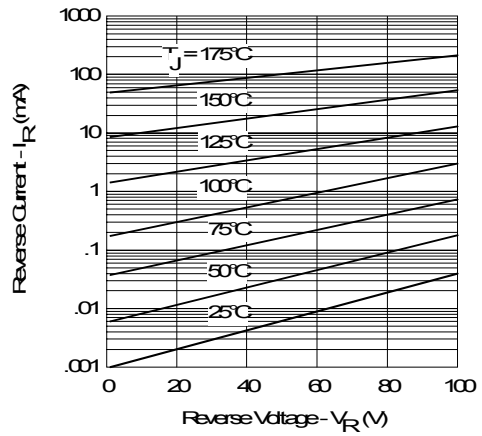


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage (Per Leg)

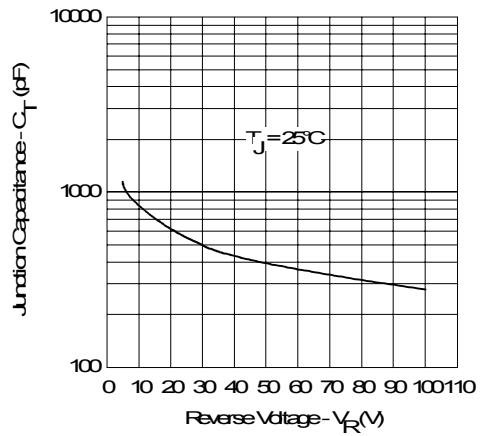


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage (Per Leg)

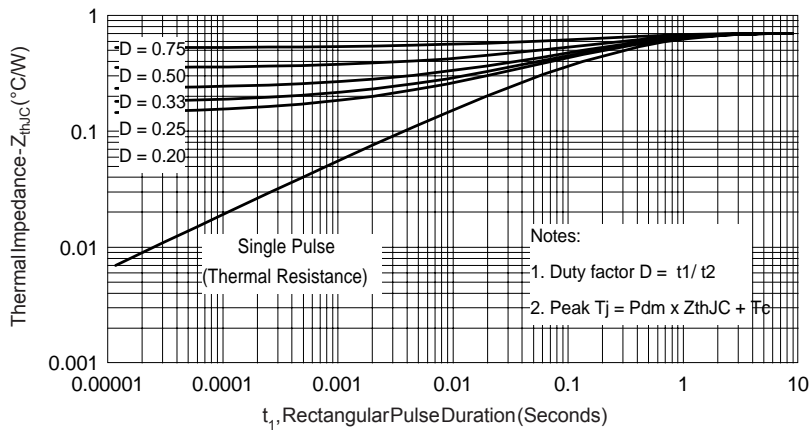


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics (Per Leg)

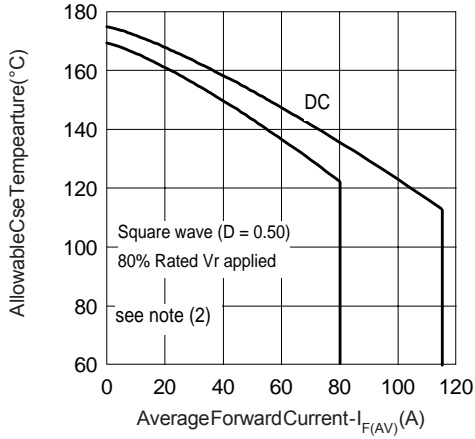


Fig. 5- Max. Allowable Case Temperature Vs. Average Forward Current (Per Leg)

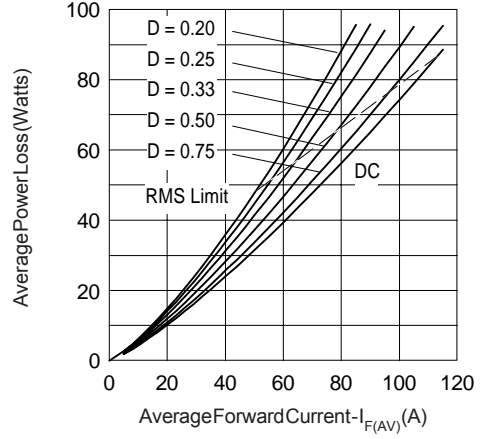


Fig. 6- Forward Power Loss Characteristics (Per Leg)

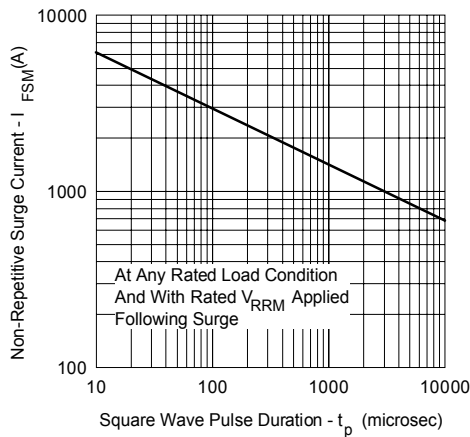


Fig. 7- Max. Non-Repetitive Surge Current (Per Leg)

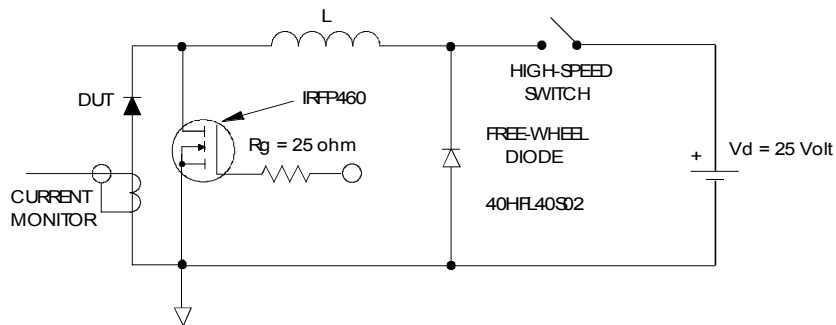


Fig. 8- Unclamped Inductive Test Circuit

(2) Formula used: $T_c = T_j - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_{R1} (1 - D)$; $I_{R1} @ V_{R1} = 80\%$ rated V_R applied



Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

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